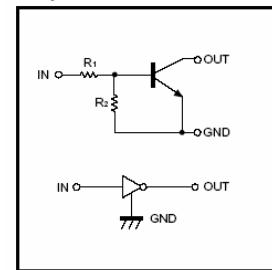


## Features

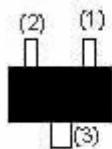
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



## PIN CONNECTIONS AND MARKING

**DTC144EE**

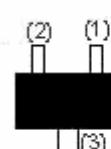


1.IN  
2.GND  
3.OUT

SOT-523

Addreviated symbol: 26

**DTC144EUA**

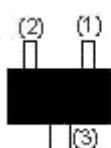


1.IN  
2.GND  
3.OUT

SOT-323

Addreviated symbol: 26

**DTC144EKA**

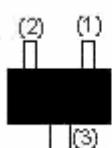


1.IN  
2.GND  
3.OUT

SOT-23-3L

Addreviated symbol: 26

**DTC144ECA**

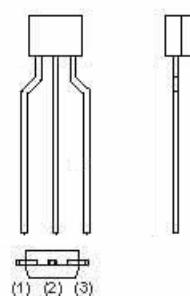


1.IN  
2.GND  
3.OUT

SOT-23

Addreviated symbol: 26

**DTC144ESA**



1.GND  
2.OUT  
3.IN

TO-92S

**Absolute maximum ratings(Ta=25°C)**

Parameter	Symbol	Limits (DTC144E□ )					Unit				
		E	UA	CA	KA	SA					
Collector-base voltage	V <sub>(BR)CBO</sub>	50					V				
Collector-emitter voltage	V <sub>(BR)CEO</sub>	50					V				
Emitter-base voltage	V <sub>(BR)EBO</sub>	5					V				
Collector current	I <sub>C</sub>	100					mA				
Collector Power dissipation	P <sub>C</sub>	150	200		300		mW				
Junction temperature	T <sub>j</sub>	150					°C				
Storage temperature	T <sub>stg</sub>	-55~150					°C				

**Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			0.5	V	V <sub>CC</sub> =5V , I <sub>O</sub> =100μA
	V <sub>I(on)</sub>	3				V <sub>O</sub> =0.3V , I <sub>O</sub> =2mA
Output voltage	V <sub>O(on)</sub>			0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>			0.18	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>			0.5	μA	V <sub>CC</sub> =50V , V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	68				V <sub>O</sub> =5V , I <sub>O</sub> =5mA
Input resistance	R <sub>I</sub>	32.9	47	61.1	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =10V , I <sub>O</sub> =5mA,f=100MHz

**Typical Characteristics**
